NSN 5961-01-159-7699

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View Online at https://aerobasegroup.com/nsn/5961-01-159-7699 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.300 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 breakdown voltage, collector to emitter, sustained and 700.0 collector to emitter voltage, dc and 700.0 collector to base voltage, dc and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 75.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 49956-g111853 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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